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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, I ² C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	DMA, I ² S, POR, PWM, WDT
Number of I/O	86
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	64K x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 3.6V
Data Converters	A/D 17x12b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f302vet6tr

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3.18.6 SysTick timer

This timer is dedicated to real-time operating systems, but could also be used as a standard down counter. It features:

- A 24-bit down counter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0.
- Programmable clock source

3.19 Real-time clock (RTC) and backup registers

The RTC and the 16 backup registers are supplied through a switch that takes power from either the V_{DD} supply when present or the V_{BAT} pin. The backup registers are sixteen 32-bit registers used to store 64 bytes of user application data when V_{DD} power is not present.

They are not reset by a system or power reset, or when the device wakes up from Standby mode.

The RTC is an independent BCD timer/counter. It supports the following features:

- Calendar with subsecond, seconds, minutes, hours (12 or 24 format), week day, date, month, year, in BCD (binary-coded decimal) format.
- Reference clock detection: a more precise second source clock (50 or 60 Hz) can be used to enhance the calendar precision.
- Automatic correction for 28, 29 (leap year), 30 and 31 days of the month.
- Two programmable alarms with wake up from Stop and Standby mode capability.
- On-the-fly correction from 1 to 32767 RTC clock pulses. This can be used to synchronize it with a master clock.
- Digital calibration circuit with 1 ppm resolution, to compensate for quartz crystal inaccuracy.
- Three anti-tamper detection pins with programmable filter. The MCU can be woken up from Stop and Standby modes on tamper event detection.
- Timestamp feature which can be used to save the calendar content. This function can be triggered by an event on the timestamp pin, or by a tamper event. The MCU can be woken up from Stop and Standby modes on timestamp event detection.
- 17-bit Auto-reload counter for periodic interrupt with wakeup from STOP/STANDBY capability.

The RTC clock sources can be:

- A 32.768 kHz external crystal
- A resonator or oscillator
- The internal low-power RC oscillator (typical frequency of 40 kHz)
- The high-speed external clock divided by 32.

3.20 Inter-integrated circuit interface (I²C)

Up to three I²C bus interfaces can operate in multimaster and slave modes. They can support standard (up to 100 kHz), fast (up to 400 kHz) and fast mode + (up to 1 MHz) modes.

communication mode and have LIN Master/Slave capability. The USART interfaces can be served by the DMA controller.

3.22 Universal asynchronous receiver transmitter (UART)

The STM32F302xD/E devices have 2 embedded universal asynchronous receiver transmitters (UART4, and UART5). The UART interfaces support IrDA SIR ENDEC, multiprocessor communication mode and single-wire half-duplex communication mode. The UART4 interface can be served by the DMA controller.

Refer to [Table 8](#) for the features available in all U(S)ART interfaces.

Table 8. USART features

USART modes/features ⁽¹⁾	USART1	USART2	USART3	UART4	UART5
Hardware flow control for modem	X	X	X	-	-
Continuous communication using DMA	X	X	X	X	-
Multiprocessor communication	X	X	X	X	X
Synchronous mode	X	X	X	-	-
Smartcard mode	X	X	X	-	-
Single-wire half-duplex communication	X	X	X	X	X
IrDA SIR ENDEC block	X	X	X	X	X
LIN mode	X	X	X	X	X
Dual clock domain and wakeup from Stop mode	X	X	X	X	X
Receiver timeout interrupt	X	X	X	X	X
Modbus communication	X	X	X	X	X
Auto baud rate detection	X	X	X	-	-
Driver Enable	X	X	X	-	-

1. X = supported.

3.23 Serial peripheral interface (SPI)/Inter-integrated sound interfaces (I²S)

Up to four SPIs are able to communicate up to 18 Mbit/s in slave and master modes in full-duplex and half-duplex communication modes. The 3-bit prescaler gives 8 master mode frequencies and the frame size is configurable from 4 bits to 16 bits.

Two standard I²S interfaces (multiplexed with SPI2 and SPI3) supporting four different audio standards can operate as master or slave at half-duplex and full duplex communication modes. They can be configured to transfer 16 and 24 or 32 bits with 16-bit or 32-bit data resolution and synchronized by a specific signal. Audio sampling frequency from 8 kHz up to 192 kHz can be set by 8-bit programmable linear prescaler. When operating in master mode it can output a clock for an external audio component at 256 times the sampling frequency.

Refer to [Table 9](#) for the features available in SPI1, SPI2, SPI3 and SPI4.

Table 13. STM32F302xD/E pin definitions (continued)

Pin number				Pin name (function after reset)	Pin type	I/O structure	Notes	Alternate functions	Additional functions
LQFP64	LQFP100	WLCSP100	LQFP144						
-	82	C3	115	PD1	I/O	FT	(1)	EVENTOUT, CAN_TX, FMC_D3	-
54	83	A4	116	PD2	I/O	FT	-	EVENTOUT, TIM3_ETR, UART5_RX	-
-	84	B4	117	PD3	I/O	FT	(1)	EVENTOUT, TIM2_CH1/TIM2_ETR, USART2_CTS, FMC_CLK	-
-	85	C4	118	PD4	I/O	FT	(1)	EVENTOUT, TIM2_CH2, USART2_RTS, FMC_NOE	-
-	86	-	119	PD5	I/O	FT	(1)	EVENTOUT, USART2_TX, FMC_NWE	-
-	-	-	120	VSS	S	-	(1)	-	-
-	-	-	121	VDD	S	-	(1)	-	-
-	87	-	122	PD6	I/O	FT	(1)	EVENTOUT, TIM2_CH4, USART2_RX, FMC_NWAIT	-
-	88	D4	123	PD7	I/O	FT	(1)	EVENTOUT, TIM2_CH3, USART2_CK, FMC_NE1/FMC_NCE2	-
-	-	-	124	PG9	I/O	FT	(1)	EVENTOUT, FMC_NE2/FMC_NCE3	-
-	-	-	125	PG10	I/O	FT	(1)	EVENTOUT, FMC_NCE4_1/FMC_NE3	-
-	-	-	126	PG11	I/O	FT	(1)	EVENTOUT, FMC_NCE4_2	-
-	-	-	127	PG12	I/O	FT	(1)	EVENTOUT, FMC_NE4	-
-	-	-	128	PG13	I/O	FT	(1)	EVENTOUT, FMC_A24	-
-	-	-	129	PG14	I/O	FT	(1)	EVENTOUT, FMC_A25	-
-	-	-	130	VSS	S	-	(1)	-	-
-	-	-	131	VDD	S	-	(1)	-	-
-	-	-	132	PG15	I/O	FT	(1)	EVENTOUT	-

Table 14. STM32F302xD/E alternate function mapping (continued)

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
		SYS_AF	TIM2/15/ 16/17/E VENT	I2C3/TIM1 /2/3/4/8/20 /15/GPCO MP1	I2C3//15/ TSC	I2C1/2/TI M1/8/16/ 17	SPI1/SPI2 /I2S2/SPI3 /I2S3/SPI4 /UART4/5/ Infrared	SPI2/I2S2/ SPI3/I2S3/ TIM1/8/20/ Infrared	USART1/2 /3/CAN/GP COMP6	I2C3/GPC OMP1/2/3/ 4/5/6	CAN/TIM1 /8/15	TIM2/3/ 4/8/17	TIM1/8	FSMC /TIM1	-	-	EVENT
Port E	PE12	-	EVENT OUT	TIM1_ CH3N	-	-	SPI4_SCK	-	-	-	-	-	-	FMC_D9	-	-	-
	PE13	-	EVENT OUT	TIM1_ CH3	-	-	SPI4_ MISO	-	-	-	-	-	-	FMC_ D10	-	-	-
	PE14	-	EVENT OUT	TIM1_ CH4	-	-	SPI4_ MOSI	TIM1_ BKIN2	-	-	-	-	-	FMC_ D11	-	-	-
	PE15	-	EVENT OUT	TIM1_ BKIN	-	-	-	-	USART3_ RX	-	-	-	-	FMC_ D12	-	-	-
Port F	PF0	-	EVENT OUT	-	-	I2C2_SDA	SPI2_NSS /I2S2_WS	TIM1_ CH3N	-	-	-	-	-	-	-	-	-
	PF1	-	EVENT OUT	-	-	I2C2_SCL	SPI2_SCK /I2S2_CK	-	-	-	-	-	-	-	-	-	-
	PF2	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_A2	-	-	-
	PF3	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_A3	-	-	-
	PF4	-	EVENT OUT	COMP1_ OUT	-	-	-	-	-	-	-	-	-	FMC_A4	-	-	-
	PF5	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_A5	-	-	-
	PF6	-	EVENT OUT	TIM4_ CH4	-	I2C2_SCL	-	-	USART3_ RTS	-	-	-	-	FMC_ NIORD	-	-	-
	PF7	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_ NREG	-	-	-

Table 14. STM32F302xD/E alternate function mapping (continued)

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
		SYS_AF	TIM2/15/ 16/17/E VENT	I2C3/TIM1 /2/3/4/8/20 /15/GPCO MP1	I2C3//15/ TSC	I2C1/2/TI M1/8/16/ 17	SPI1/SPI2 /I2S2/SPI3 /I2S3/SPI4 /UART4/5/ Infrared	SPI2/I2S2/ SPI3/I2S3/ TIM1/8/20/ Infrared	USART1/2 /3/CAN/GP COMP6	I2C3/GPC OMP1/2/3/ 4/5/6	CAN/TIM1 /8/15	TIM2/3/ 4/8/17	TIM1/8	FSMC /TIM1	-	-	EVENT
Port G	PG5	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_ A15	-	-	-
	PG6	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_ INT2	-	-	-
	PG7	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_ INT3	-	-	-
	PG8	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	-	-	-	-
	PG9	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_NE 2/FMC_ NCE3	-	-	-
	PG10	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_ NCE4_1/ FMC_ NE3	-	-	-
	PG11	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_ NCE4_2	-	-	-
	PG12	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_ NE4	-	-	-
	PG13	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_ A24	-	-	-
	PG14	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	FMC_ A25	-	-	-
	PG15	-	EVENT OUT	-	-	-	-	-	-	-	-	-	-	-	-	-	-

Table 32. Switching output I/O current consumption

Symbol	Parameter	Conditions ⁽¹⁾	I/O toggling frequency (f _{SW})	Typ	Unit
I _{SW}	I/O current consumption	$V_{DD} = 3.3\text{ V}$ $C_{ext} = 0\text{ pF}$ $C = C_{INT} + C_{EXT} + C_S$	2 MHz	0.90	mA
			4 MHz	0.93	
			8 MHz	1.16	
			18 MHz	1.60	
			36 MHz	2.51	
			48 MHz	2.97	
		$V_{DD} = 3.3\text{ V}$ $C_{ext} = 10\text{ pF}$ $C = C_{INT} + C_{EXT} + C_S$	2 MHz	0.93	
			4 MHz	1.06	
			8 MHz	1.47	
			18 MHz	2.26	
			36 MHz	3.39	
			48 MHz	5.99	
		$V_{DD} = 3.3\text{ V}$ $C_{ext} = 22\text{ pF}$ $C = C_{INT} + C_{EXT} + C_S$	2 MHz	1.03	
			4 MHz	1.30	
			8 MHz	1.79	
			18 MHz	3.01	
			36 MHz	5.99	
		$V_{DD} = 3.3\text{ V}$ $C_{ext} = 33\text{ pF}$ $C = C_{INT} + C_{EXT} + C_S$	2 MHz	1.10	
			4 MHz	1.31	
			8 MHz	2.06	
			18 MHz	3.47	
			36 MHz	8.35	
		$V_{DD} = 3.3\text{ V}$ $C_{ext} = 47\text{ pF}$ $C = C_{INT} + C_{EXT} + C_S$	2 MHz	1.20	
			4 MHz	1.54	
			8 MHz	2.46	
			18 MHz	4.51	
			36 MHz	9.98	

1. CS = 5 pF (estimated value).

Table 50. Asynchronous multiplexed PSRAM/NOR read timings⁽¹⁾ (continued)

Symbol	Parameter	Min	Max	Unit
$t_{v(BL_NE)}$	FMC_NEx low to FMC_BL valid	-	2	ns
$t_{su(Data_NE)}$	Data to FMC_NEx high setup time	THCLK	-	
$t_{su(Data_NOE)}$	Data to FMC_NOE high setup time	THCLK+1	-	
$t_h(Data_NE)$	Data hold time after FMC_NEx high	0	-	
$t_h(Data_NOE)$	Data hold time after FMC_NOE high	0	-	

1. Based on characterization, not tested in production.

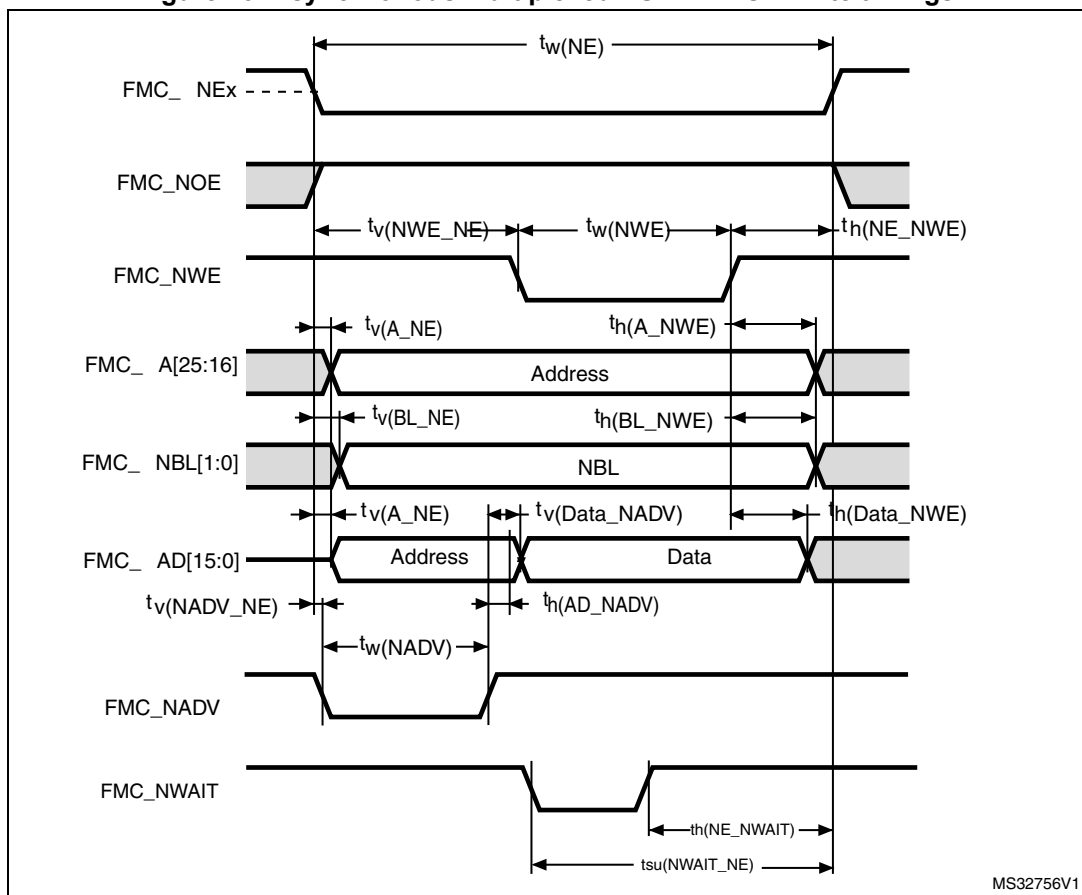
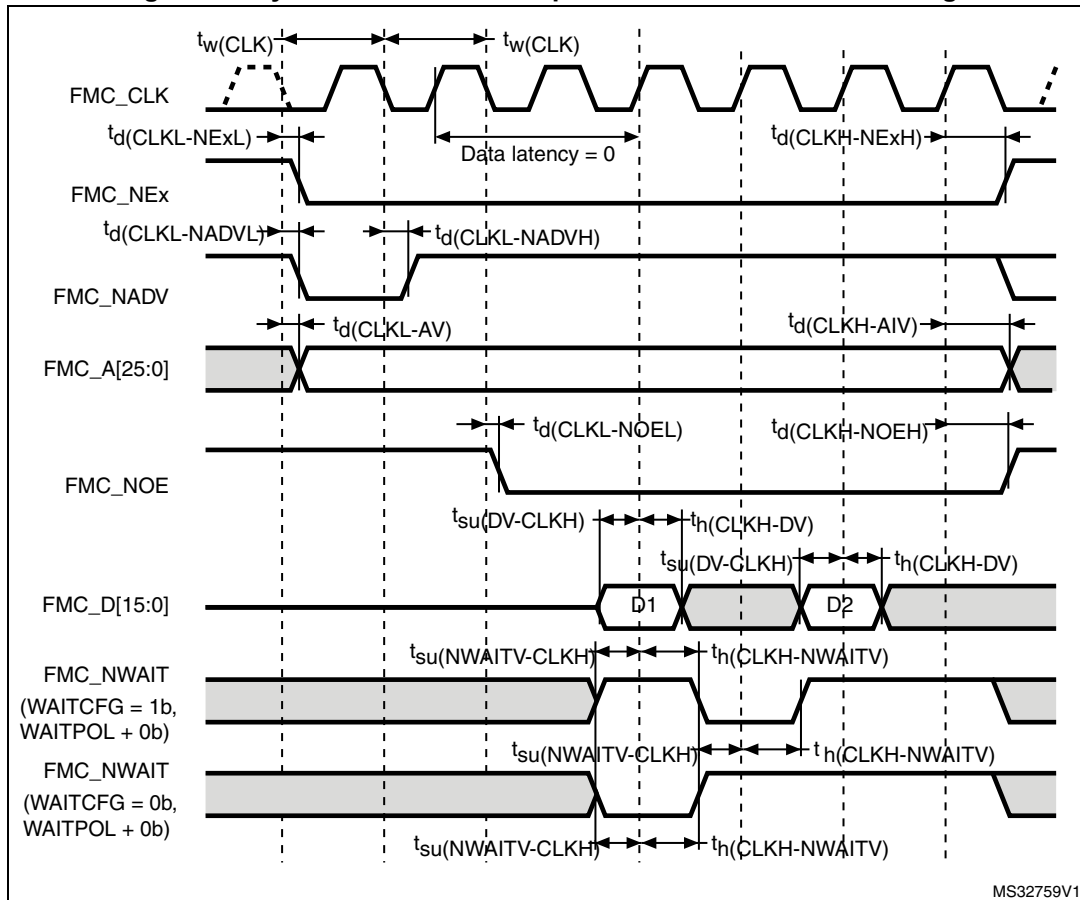
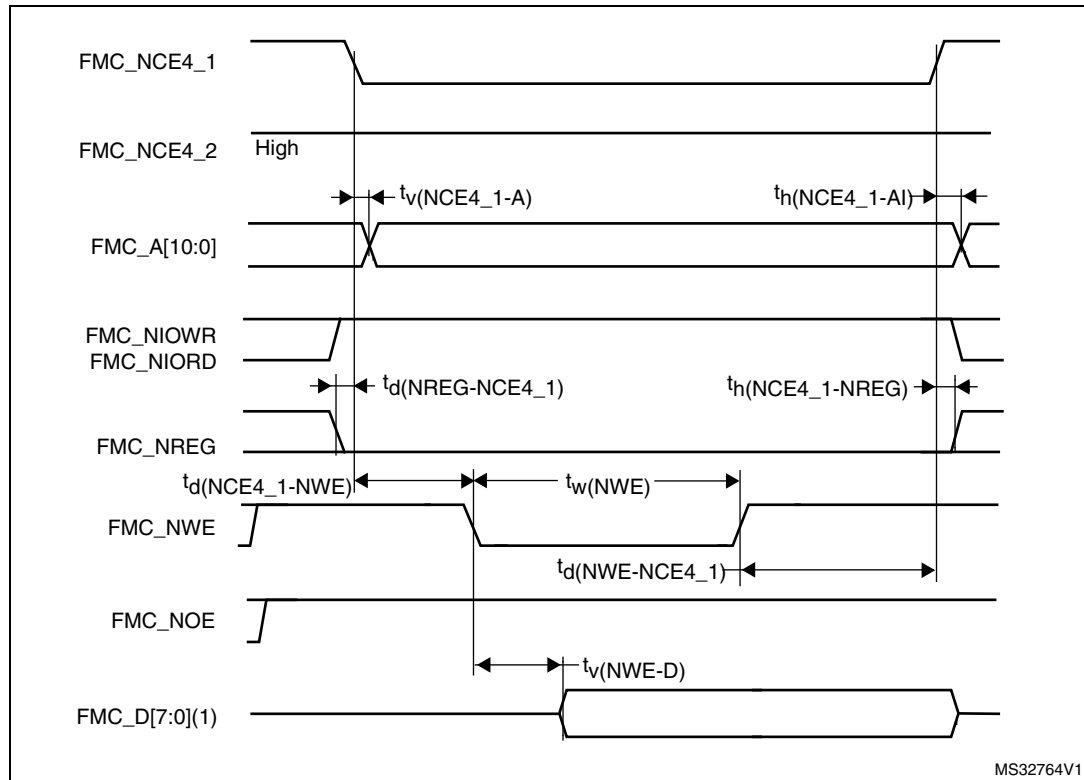
Figure 23. Asynchronous multiplexed PSRAM/NOR write timings

Figure 26. Synchronous non-multiplexed NOR/PSRAM read timings

Table 55. Synchronous non-multiplexed NOR/PSRAM read timings⁽¹⁾

Symbol	Parameter	Min	Max	Unit
$t_{w(CLK)}$	FMC_CLK period	2THCLK-1	-	ns
$t_{d(CLKL-NExL)}$	FMC_CLK low to FMC_NEx low ($x=0..2$)	-	5	
$t_{d(CLKH-NExH)}$	FMC_CLK high to FMC_NEx high ($x=0..2$)	THCLK+1	-	
$t_{d(CLKL-NADV)}$	FMC_CLK low to FMC_NADV low	-	7	
$t_{d(CLKL-NADVH)}$	FMC_CLK low to FMC_NADV high	2.5	-	
$t_{d(CLKL-AV)}$	FMC_CLK low to FMC_Ax valid ($x=16..25$)	-	7	
$t_{d(CLKH-AIV)}$	FMC_CLK high to FMC_Ax invalid ($x=16..25$)	THCLK	-	
$t_{d(CLKL-NOEL)}$	FMC_CLK low to FMC_NOE low	-	6	
$t_{d(CLKH-NOEH)}$	FMC_CLK high to FMC_NOE high	THCLK+1	-	
$t_{su(DV-CLKH)}$	FMC_D[15:0] valid data before FMC_CLK high	3.5	-	

Figure 31. PC Card/CompactFlash controller waveforms for attribute memory write access

1. Only data bits 0...7 are driven (bits 8...15 remains Hi-Z).

Table 58. Switching characteristics for PC Card/CF read and write cycles in I/O space⁽¹⁾

Symbol	Parameter	Min	Max	Unit
$t_{w(NIOWR)}$	FMC_NIOWR low width	8THCLK-0.5	-	ns
$t_{v(NIOWR-D)}$	FMC_NIOWR low to FMC_D[15:0] valid	-	5.5	
$t_{h(NIOWR-D)}$	FMC_NIOWR high to FMC_D[15:0] invalid	4THCLK-0.5	-	
$t_{d(NCE4_1-NIOWR)}$	FMC_NCE4_1 low to FMC_NIOWR valid	-	5THCLK+1	
$t_{h(NCEX-NIOWR)}$	FMC_NCEX high to FMC_NIOWR invalid	4THCLK+0.5	-	
$t_{d(NIORD-NCEX)}$	FMC_NCEX low to FMC_NIORD valid	-	5THCLK	
$t_{h(NCEX-NIORD)}$	FMC_NCEX high to FMC_NIORD) valid	6THCLK+2	-	
$t_{w(NIORD)}$	FMC_NIORD low width	8THCLK-1	8THCLK+1	
$t_{su(D-NIORD)}$	FMC_D[15:0] valid before FMC_NIORD high	THCLK+2	-	
$t_{d(NIORD-D)}$	FMC_D[15:0] valid after FMC_NIORD high	0	-	

1. Based on characterization, not tested in production.

Table 65. I/O current injection susceptibility (continued)

Symbol	Description	Functional susceptibility		Unit
		Negative injection	Positive injection	
I_{INJ}	Injected current on PB0, PB1, PE7, PE8, PE9, PE10, PE11, PE12, PE13, PE14, PE15, PB12, PB13, PB14, P15, PD8, PD9, PD10, PD11, PD12, PD13, PD14 with induced leakage current on other pins from this group less than -50 μ A or more than +400 μ A	-5	+5	mA
	Injected current on any other FT and FTf pins	-5	NA	
	Injected current on any other pins	-5	+5	

Note: It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative currents.

6.3.15 I/O port characteristics

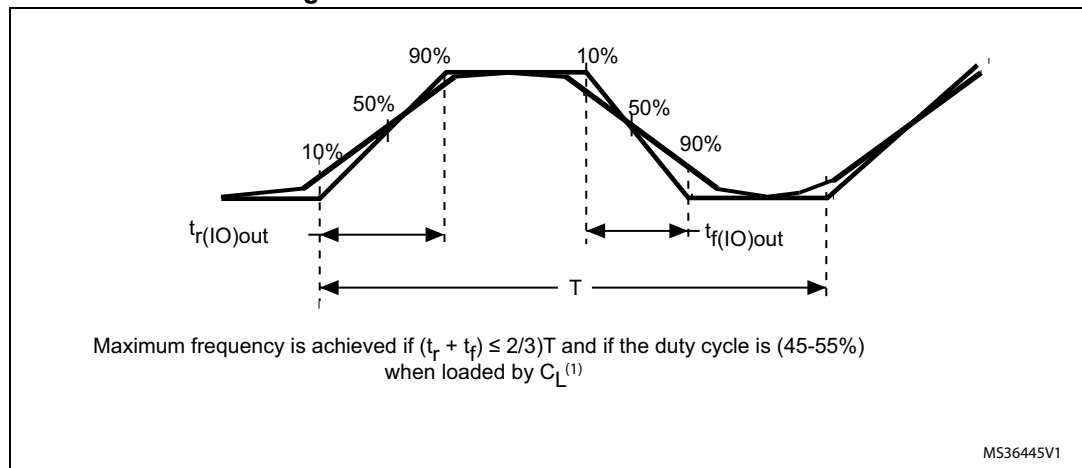
General input/output characteristics

Unless otherwise specified, the parameters given in [Table 66](#) are derived from tests performed under the conditions summarized in [Table 19](#). All I/Os are CMOS and TTL compliant.

Table 66. I/O static characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IL}	Low level input voltage	TC and TTa I/O	-	-	$0.3 V_{DD} + 0.07^{(1)}$	V
		FT and FTf I/O	-	-	$0.475 V_{DD} - 0.2^{(1)}$	
		BOOT0	-	-	$0.3 V_{DD} - 0.3^{(1)}$	
		All I/Os except BOOT0	-	-	$0.3 V_{DD}^{(2)}$	
V_{IH}	High level input voltage	TC and TTa I/O	$0.445 V_{DD} + 0.398^{(1)}$	-	-	V
		FT and FTf I/O	$0.5 V_{DD} + 0.2^{(1)}$	-	-	
		BOOT0	$0.2 V_{DD} + 0.95^{(1)}$	-	-	
		All I/Os except BOOT0	$0.7 V_{DD}^{(2)}$	-	-	
V_{hys}	Schmitt trigger hysteresis	TC and TTa I/O	-	200 ⁽¹⁾	-	mV
		FT and FTf I/O	-	100 ⁽¹⁾	-	
		BOOT0	-	300 ⁽¹⁾	-	

Figure 40. I/O AC characteristics definition



1. See [Table 68: I/O AC characteristics](#).

6.3.16 NRST pin characteristics

The NRST pin input driver uses CMOS technology. It is connected to a permanent pull-up resistor, R_{PU} (see [Table 66](#)).

Unless otherwise specified, the parameters given in [Table 69](#) are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in [Table 19](#).

Table 69. NRST pin characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{IL(NRST)}^{(1)}$	NRST Input low level voltage	-	-	-	$0.3V_{DD} + 0.07^{(1)}$	V
$V_{IH(NRST)}^{(1)}$	NRST Input high level voltage	-	$0.445V_{DD} + 0.398^{(1)}$	-	-	
$V_{hys(NRST)}$	NRST Schmitt trigger voltage hysteresis	-	-	200	-	mV
R_{PU}	Weak pull-up equivalent resistor ⁽²⁾	$V_{IN} = V_{SS}$	25	40	55	kΩ
$V_{F(NRST)}^{(1)}$	NRST Input filtered pulse	-	-	-	100 ⁽¹⁾	ns
$V_{NF(NRST)}^{(1)}$	NRST Input not filtered pulse	-	500 ⁽¹⁾	-	-	ns

1. Guaranteed by design, not tested in production.

2. The pull-up is designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance must be minimum (~10% order).

Table 71. IWDG min/max timeout period at 40 kHz (LSI) ⁽¹⁾

Prescaler divider	PR[2:0] bits	Min timeout (ms) RL[11:0]=0x000	Max timeout (ms) RL[11:0]=0xFFFF
/4	0	0.1	409.6
/8	1	0.2	819.2
/16	2	0.4	1638.4
/32	3	0.8	3276.8
/64	4	1.6	6553.6
/128	5	3.2	13107.2
/256	7	6.4	26214.4

1. These timings are given for a 40 kHz clock but the microcontroller internal RC frequency can vary from 30 to 60 kHz. Moreover, given an exact RC oscillator frequency, the exact timings still depend on the phasing of the APB interface clock versus the LSI clock so that there is always a full RC period of uncertainty.

Table 72. WWDG min-max timeout value @72 MHz (PCLK)⁽¹⁾

Prescaler	WDGTB	Min timeout value	Max timeout value
1	0	0.05687	3.6409
2	1	0.1137	7.2817
4	2	0.2275	14.564
8	3	0.4551	29.127

1. Guaranteed by design, not tested in production.

6.3.18 Communications interfaces

I²C interface characteristics

The I²C interface meets the timings requirements of the I²C-bus specification and user manual rev.03 for:

- Standard-mode (Sm): with a bit rate up to 100 kbit/s
- Fast-mode (Fm): with a bit rate up to 400 kbit/s
- Fast-mode Plus (Fm+): with a bit rate up to 1Mbits/s

The I²C timings requirements are guaranteed by design when the I²C peripheral is properly configured (refer to Reference manual).

The SDA and SCL I/O requirements are met with the following restrictions: the SDA and SCL I/O pins are “true” open-drain. When configured as open-drain, the PMOS connected between the I/O pin and VDDIOx is disabled, but is still present. Only FTf I/O pins support Fm+ low level output current maximum requirement. Refer to [Section 6.3.15: I/O port characteristics](#).

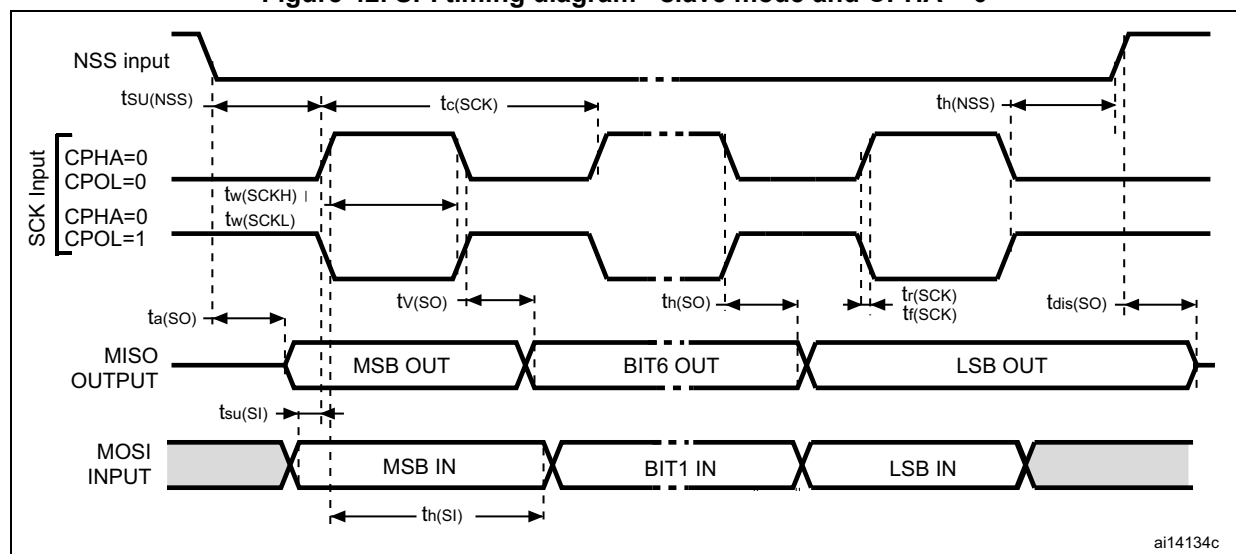
All I²C I/Os embed an analog filter, refer to the [Table 73: I2C analog filter characteristics](#).

Table 74. SPI characteristics⁽¹⁾ (continued)

Symbol	Parameter	Conditions	Min	Typ.	Max	Unit
$t_{V(SO)}$	Data output valid time	Slave mode $2.7\text{ V} < V_{DD} < 3.6\text{ V}$	-	15	22	
		Slave mode $2\text{ V} < V_{DD} < 3.6\text{ V}$	-	15	30	
$t_{V(MO)}$		Master mode	-	2	4.5	
$t_{h(SO)}$	Data output hold time	Slave mode	9	-	-	
$t_{h(MO)}$		Master mode	0	-	-	

1. Data based on characterization results, not tested in production.
2. The maximum frequency in Slave transmitter mode is determined by the sum of $t_{V(SO)}$ and $t_{SU(MI)}$ which has to fit into SCK low or high phase preceding the SCK sampling edge. This value can be achieved when the SPI communicates with a master having $t_{SU(MI)} = 0$ while $\text{Duty}_{(SCK)} = 50\%$.

Figure 42. SPI timing diagram - slave mode and CPHA = 0



ai14134c

Table 79. ADC characteristics (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_S^{(1)}$	Sampling time	$f_{ADC} = 72 \text{ MHz}$	0.021	-	8.35	μs
		-	1.5	-	601.5	$1/f_{ADC}$
$T_{ADCVREG_STUP}^{(1)}$	ADC Voltage Regulator Start-up time	-	-	-	10	μs
$t_{CONV}^{(1)}$	Total conversion time (including sampling time)	$f_{ADC} = 72 \text{ MHz}$ Resolution = 12 bits	0.19	-	8.52	μs
		Resolution = 12 bits	14 to 614 (t_S for sampling + 12.5 for successive approximation)			$1/f_{ADC}$
CMIR	Common Mode Input signal range	ADC differential mode	$(V_{SSA} + V_{REF+})/2 - 0.18$	$(V_{SSA} + V_{REF+})/2$	$(V_{SSA} + V_{REF+})/2 + 0.18$	V

1. Data guaranteed by design, not tested in Production.
2. V_{REF+} can be internally connected to V_{DDA} and V_{REF-} can be internally connected to V_{SSA} , depending on the package. Refer to [Section 4: Pinout and pin description](#) for further details.

Figure 48. ADC typical current consumption on VDDA pin

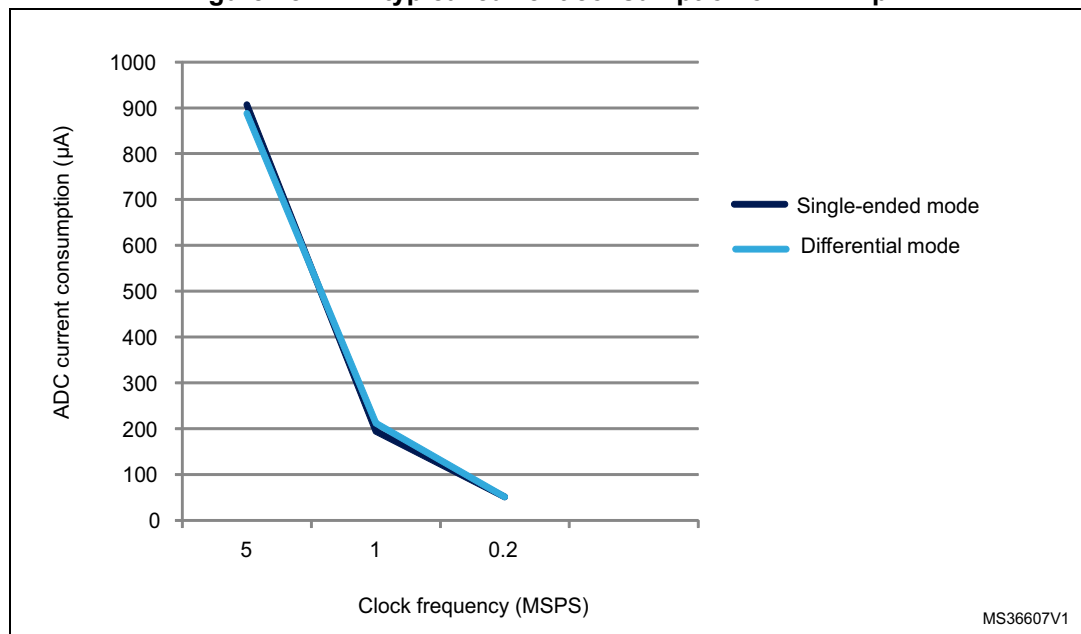


Table 83. ADC accuracy - limited test conditions, 64-pin packages⁽¹⁾⁽²⁾

Symbol	Parameter	Conditions			Min (3)	Typ	Max (3)	Unit
ET	Total unadjusted error	ADC clock freq. ≤ 72 MHz Sampling freq. ≤ 5 Msps V _{DDA} = 3.3 V 25°C 64-pin package	Single ended	Fast channel 5.1 Ms	-	±4	±4.5	LSB
				Slow channel 4.8 Ms	-	±5.5	±6	
Differential	Fast channel 5.1 Ms		-	±3.5	±4			
	Slow channel 4.8 Ms		-	±3.5	±4			
EO	Offset error		Single ended	Fast channel 5.1 Ms	-	±2	±2	
				Slow channel 4.8 Ms	-	±1.5	±2	
			Differential	Fast channel 5.1 Ms	-	±1.5	±2	
				Slow channel 4.8 Ms	-	±1.5	±2	
EG	Gain error		Single ended	Fast channel 5.1 Ms	-	±3	±4	
				Slow channel 4.8 Ms	-	±5	±5.5	
			Differential	Fast channel 5.1 Ms	-	±3	±3	
				Slow channel 4.8 Ms	-	±3	±3.5	
ED	Differential linearity error	Single ended	Fast channel 5.1 Ms	-	±1	±1		
			Slow channel 4.8 Ms	-	±1	±1		
		Differential	Fast channel 5.1 Ms	-	±1	±1		
			Slow channel 4.8 Ms	-	±1	±1		
EL	Integral linearity error	Single ended	Fast channel 5.1 Ms	-	±1.5	±2		
			Slow channel 4.8 Ms	-	±2	±3		
		Differential	Fast channel 5.1 Ms	-	±1.5	±1.5		
			Slow channel 4.8 Ms	-	±1.5	±2		
ENOB ⁽⁴⁾	Effective number of bits		Single ended	Fast channel 5.1 Ms	10.8	10.8	-	bit
				Slow channel 4.8 Ms	10.8	10.8	-	
			Differential	Fast channel 5.1 Ms	11.2	11.3	-	
				Slow channel 4.8 Ms	11.2	11.3	-	
SINAD ⁽⁴⁾	Signal-to-noise and distortion ratio		Single ended	Fast channel 5.1 Ms	66	67	-	dB
				Slow channel 4.8 Ms	66	67	-	
			Differential	Fast channel 5.1 Ms	69	70	-	
				Slow channel 4.8 Ms	69	70	-	

Table 87. Comparator characteristics⁽¹⁾ (continued)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
TV_{OFFSET}	Total offset variation	Full temperature range	-	-	3	mV
I_{DDA}	COMP current consumption	-	-	400	600	μA

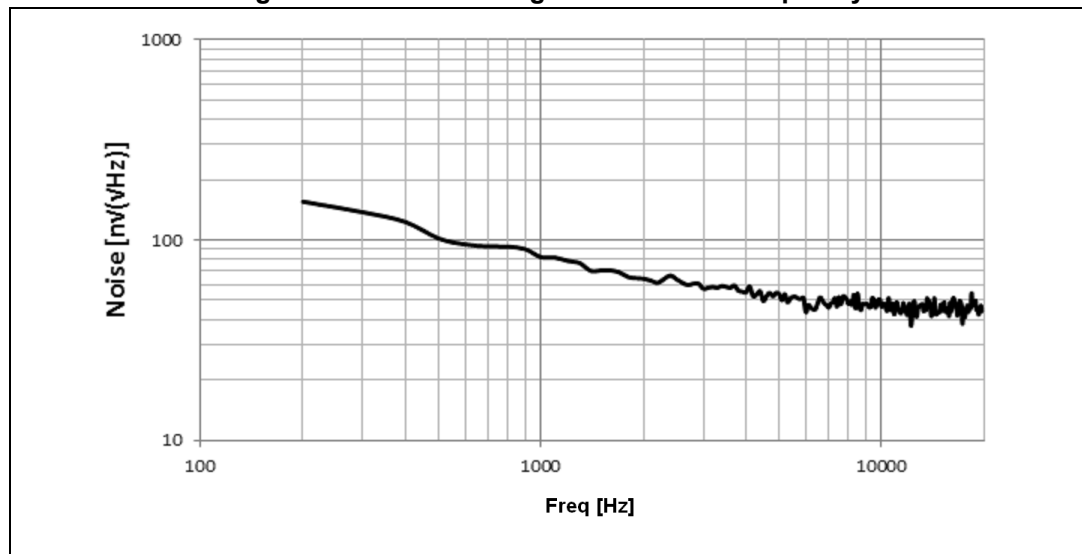
1. Guaranteed by design, not tested in production.

Table 88. Operational amplifier characteristics⁽¹⁾ (continued)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
PGA gain	Non inverting gain value	-	-	2	-	-
			-	4	-	-
			-	8	-	-
			-	16	-	-
R _{network}	R2/R1 internal resistance values in PGA mode ⁽³⁾	Gain=2	-	5.4/5.4	-	kΩ
		Gain=4	-	16.2/5.4	-	
		Gain=8	-	37.8/5.4	-	
		Gain=16	-	40.5/2.7	-	
PGA gain error	PGA gain error	-	-1%	-	1%	-
I _{bias}	OPAMP input bias current	-	-	-	±0.2 ⁽⁴⁾	μA
PGA BW	PGA bandwidth for different non inverting gain	PGA Gain = 2, Cload = 50pF, Rload = 4 KΩ	-	4	-	MHz
		PGA Gain = 4, Cload = 50pF, Rload = 4 KΩ	-	2	-	
		PGA Gain = 8, Cload = 50pF, Rload = 4 KΩ	-	1	-	
		PGA Gain = 16, Cload = 50pF, Rload = 4 KΩ	-	0.5	-	
en	Voltage noise density	@ 1KHz, Output loaded with 4 KΩ	-	109	-	$\frac{nV}{\sqrt{Hz}}$
		@ 10KHz, Output loaded with 4 KΩ	-	43	-	

1. Guaranteed by design, not tested in production.
2. The saturation voltage can be also limited by the Iload (drive current).
3. R2 is the internal resistance between OPAMP output and OPAMP inverting input.
R1 is the internal resistance between OPAMP inverting input and ground.
The PGA gain = 1+R2/R1
4. Mostly TTa I/O leakage, when used in analog mode.

Figure 53. OPAMP voltage noise versus frequency



6.3.23 Temperature sensor characteristics

Table 89. TS characteristics

Symbol	Parameter	Min	Typ	Max	Unit
$T_L^{(1)}$	V_{SENSE} linearity with temperature	-	± 1	± 2	$^{\circ}\text{C}$
Avg_Slope ⁽¹⁾	Average slope	4.0	4.3	4.6	mV/ $^{\circ}\text{C}$
V_{25}	Voltage at 25 $^{\circ}\text{C}$	1.34	1.43	1.52	V
$t_{START}^{(1)}$	Startup time	4	-	10	μs
$T_{S_temp}^{(1)(2)}$	ADC sampling time when reading the temperature	2.2	-	-	μs

1. Guaranteed by design, not tested in production.

2. Shortest sampling time can be determined in the application by multiple iterations.

Table 90. Temperature sensor calibration values

Calibration value name	Description	Memory address
TS_CAL1	TS ADC raw data acquired at temperature of 30 $^{\circ}\text{C}$, $V_{DDA} = 3.3\text{ V}$	0x1FFF F7B8 - 0x1FFF F7B9
TS_CAL2	TS ADC raw data acquired at temperature of 110 $^{\circ}\text{C}$, $V_{DDA} = 3.3\text{ V}$	0x1FFF F7C2 - 0x1FFF F7C3

Table 93. UFBGA100 package mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
ddd	-	-	0.100	-	-	0.0039
eee	-	-	0.150	-	-	0.0059
fff	-	-	0.050	-	-	0.0020

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 58. Recommended footprint for the UFBGA100 package

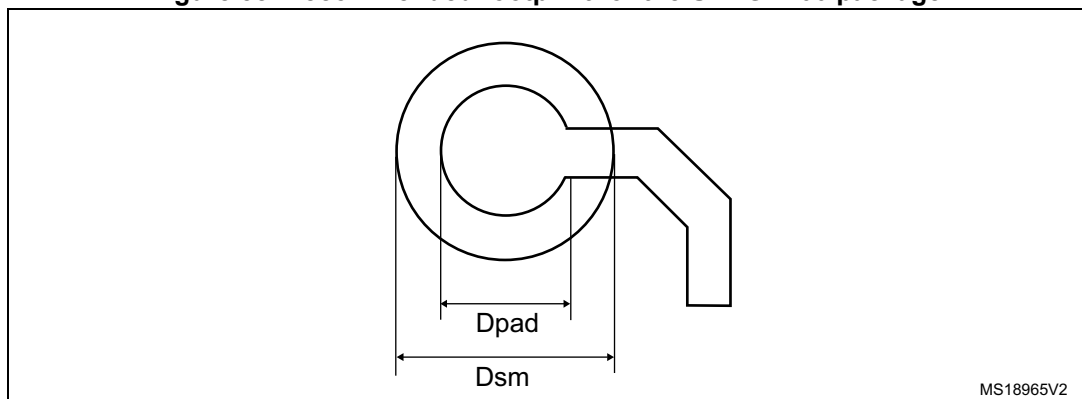


Table 94. UFBGA100 recommended PCB design rules (0.5 mm pitch BGA)

Dimension	Recommended values
Pitch	0.5
Dpad	0.27 mm
Dsm	0.35 mm typ. (depends on the soldermask registration tolerance)
Solder paste	0.27 mm aperture diameter.

Note: Non-solder mask defined (NSMD) pads are recommended.

Note: 4 to 6 mils solder paste screen printing process.